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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

E·XFl

Product Status	Obsolete
Core Processor	C166SV2
Core Size	16-Bit
Speed	80MHz
Connectivity	CANbus, EBI/EMI, I ² C, LINbus, SPI, SSC, UART/USART, USI
Peripherals	I ² S, POR, PWM, WDT
Number of I/O	76
Program Memory Size	384КВ (384К х 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	34K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 11x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP Exposed Pad
Supplier Device Package	PG-LQFP-100-8
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/sak-xe164gm-48f80l-aa

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



Summary of Features

The XE164xM types are offered with several SRAM memory sizes. **Figure 1** shows the allocation rules for PSRAM and DSRAM. Note that the rules differ:

- PSRAM allocation starts from the lower address
- DSRAM allocation starts from the higher address

For example 8 Kbytes of PSRAM will be allocated at E0'0000h-E0'1FFFh and 8 Kbytes of DSRAM will be at 00'C000h-00'DFFFh.

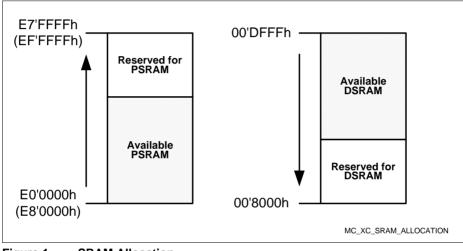


Figure 1 SRAM Allocation



Table 5 Pin Definitions and Functions (cont'd)					
Pin	Symbol	Ctrl.	Туре	Function	
6	P7.0	O0 / I	St/B	Bit 0 of Port 7, General Purpose Input/Output	
	T3OUT	01	St/B	GPT12E Timer T3 Toggle Latch Output	
	T6OUT	O2	St/B	GPT12E Timer T6 Toggle Latch Output	
	TDO_A	OH / IH	St/B	JTAG Test Data Output / DAP1 Input/Output If DAP pos. 0 or 2 is selected during start-up, an internal pull-down device will hold this pin low when nothing is driving it.	
	ESR2_1	I	St/B	ESR2 Trigger Input 1	
7	P7.3	O0 / I	St/B	Bit 3 of Port 7, General Purpose Input/Output	
	EMUX1	01	St/B	External Analog MUX Control Output 1 (ADC1)	
	U0C1_DOUT	02	St/B	USIC0 Channel 1 Shift Data Output	
	U0C0_DOUT	O3	St/B	USIC0 Channel 0 Shift Data Output	
	CCU62_CCP OS1A	I	St/B	CCU62 Position Input 1	
	TMS_C	IH	St/B	JTAG Test Mode Selection Input If JTAG pos. C is selected during start-up, an internal pull-up device will hold this pin low when nothing is driving it.	
	U0C1_DX0F	I	St/B	USIC0 Channel 1 Shift Data Input	
8	P7.1	O0 / I	St/B	Bit 1 of Port 7, General Purpose Input/Output	
	EXTCLK	O1	St/B	Programmable Clock Signal Output	
	CCU62_CTR APA	I	St/B	CCU62 Emergency Trap Input	
	BRKIN_C	I	St/B	OCDS Break Signal Input	



Table	Table 5Pin Definitions and Functions (cont'd)					
Pin	Symbol	Ctrl.	Туре	Function		
45	P2.4	O0 / I	St/B	Bit 4 of Port 2, General Purpose Input/Output		
	U0C1_DOUT	01	St/B	USIC0 Channel 1 Shift Data Output		
	TxDC0	O2	St/B	CAN Node 0 Transmit Data Output		
	CC2_CC17	O3 / I	St/B	CAPCOM2 CC17IO Capture Inp./ Compare Out.		
	A17	ОН	St/B	External Bus Interface Address Line 17		
	ESR1_0	I	St/B	ESR1 Trigger Input 0		
	U0C0_DX0F	I	St/B	USIC0 Channel 0 Shift Data Input		
	RxDC1A	I	St/B	CAN Node 1 Receive Data Input		
46	P2.5	O0 / I	St/B	Bit 5 of Port 2, General Purpose Input/Output		
	U0C0_SCLK OUT	O1	St/B	USIC0 Channel 0 Shift Clock Output		
	TxDC0	O2	St/B	CAN Node 0 Transmit Data Output		
	CC2_CC18	O3 / I	St/B	CAPCOM2 CC18IO Capture Inp./ Compare Out.		
	A18	OH	St/B	External Bus Interface Address Line 18		
	U0C0_DX1D	I	St/B	USIC0 Channel 0 Shift Clock Input		
	ESR1_10	I	St/B	ESR1 Trigger Input 10		
47	P4.2	O0 / I	St/B	Bit 2 of Port 4, General Purpose Input/Output		
	TxDC2	02	St/B	CAN Node 2 Transmit Data Output		
	CC2_CC26	O3 / I	St/B	CAPCOM2 CC26IO Capture Inp./ Compare Out.		
	CS2	ОН	St/B	External Bus Interface Chip Select 2 Output		
	T2INA	I	St/B	GPT12E Timer T2 Count/Gate Input		
	CCU62_CCP OS1B	1	St/B	CCU62 Position Input 1		



Table	Table 5 Pin Definitions and Functions (cont'd)						
Pin	Symbol	Ctrl.	Туре	Function			
57	P2.9	O0 / I	St/B	Bit 9 of Port 2, General Purpose Input/Output			
	U0C1_DOUT	01	St/B	USIC0 Channel 1 Shift Data Output			
	TxDC1	O2	St/B	CAN Node 1 Transmit Data Output			
	CC2_CC22	O3 / I	St/B	CAPCOM2 CC22IO Capture Inp./ Compare Out.			
	A22	ОН	St/B	External Bus Interface Address Line 22			
	CLKIN1	I	St/B	Clock Signal Input 1			
	TCK_A	IH	St/B	DAP0/JTAG Clock Input If JTAG pos. A is selected during start-up, an internal pull-up device will hold this pin high when nothing is driving it. If DAP pos. 0 is selected during start-up, an internal pull-down device will hold this pin low when nothing is driving it.			
58	P0.2	O0 / I	St/B	Bit 2 of Port 0, General Purpose Input/Output			
	U1C0_SCLK OUT	01	St/B	USIC1 Channel 0 Shift Clock Output			
	TxDC0	02	St/B	CAN Node 0 Transmit Data Output			
	CCU61_CC6 2	O3	St/B	CCU61 Channel 2 Output			
	A2	ОН	St/B	External Bus Interface Address Line 2			
	U1C0_DX1B	I	St/B	USIC1 Channel 0 Shift Clock Input			
	CCU61_CC6 2INA	I	St/B	CCU61 Channel 2 Input			



Table 5 Pin Definitions and Functions (cont'd)					
Pin	Symbol	Ctrl.	Туре	Function	
90	P1.4	O0 / I	St/B	Bit 4 of Port 1, General Purpose Input/Output	
	CCU62_COU T61	O1	St/B	CCU62 Channel 1 Output	
	U1C1_SELO 4	O2	St/B	USIC1 Channel 1 Select/Control 4 Output	
	U2C0_SELO 5	O3	St/B	USIC2 Channel 0 Select/Control 5 Output	
	A12	ОН	St/B	External Bus Interface Address Line 12	
	U2C0_DX2B	I	St/B	USIC2 Channel 0 Shift Control Input	
91	P10.15	O0 / I	St/B	Bit 15 of Port 10, General Purpose Input/Output	
	U1C0_SELO 2	O1	St/B	USIC1 Channel 0 Select/Control 2 Output	
	U0C1_DOUT	02	St/B	USIC0 Channel 1 Shift Data Output	
	U1C0_DOUT	O3	St/B	USIC1 Channel 0 Shift Data Output	
	ALE	ОН	St/B	External Bus Interf. Addr. Latch Enable Output	
	U0C1_DX1C	I	St/B	USIC0 Channel 1 Shift Clock Input	
92	P1.5	O0 / I	St/B	Bit 5 of Port 1, General Purpose Input/Output	
	CCU62_COU T60	O1	St/B	CCU62 Channel 0 Output	
	U1C1_SELO 3	O2	St/B	USIC1 Channel 1 Select/Control 3 Output	
	BRKOUT	O3	St/B	OCDS Break Signal Output	
	A13	ОН	St/B	External Bus Interface Address Line 13	
	U2C0_DX0C	I	St/B	USIC2 Channel 0 Shift Data Input	



General Device Information

Table 5 Pin Definitions and Functions (cont'd)					
Pin	Symbol	Ctrl.	Туре	Function	
97	PORST	1	In/B	Power On Reset Input A low level at this pin resets the XE164xM completely. A spike filter suppresses input pulses <10 ns. Input pulses >100 ns safely pass the filter. The minimum duration for a safe recognition should be 120 ns. An internal pull-up device will hold this pin high when nothing is driving it.	
98	ESR1	O0 / I	St/B	External Service Request 1 After power-up, an internal weak pull-up device holds this pin high when nothing is driving it.	
	RxDC0E	I	St/B	CAN Node 0 Receive Data Input	
	U1C0_DX0F	Ι	St/B	USIC1 Channel 0 Shift Data Input	
	U1C0_DX2C	I	St/B	USIC1 Channel 0 Shift Control Input	
	U1C1_DX0C	I	St/B	USIC1 Channel 1 Shift Data Input	
	U1C1_DX2B	I	St/B	USIC1 Channel 1 Shift Control Input	
	U2C1_DX2C	I	St/B	USIC2 Channel 1 Shift Control Input	
99	ESR0	O0 / I	St/B	External Service Request 0 After power-up, ESR0 operates as open-drain bidirectional reset with a weak pull-up.	
	U1C0_DX0E	I	St/B	USIC1 Channel 0 Shift Data Input	
	U1C0_DX2B	I	St/B	USIC1 Channel 0 Shift Control Input	
10		-	PS/M	Digital Core Supply Voltage for Domain M Decouple with a ceramic capacitor, see Data Sheet for details.	
38, 64, 88	V _{DDI1}	-	PS/1	Digital Core Supply Voltage for Domain 1 Decouple with a ceramic capacitor, see Data Sheet for details. All V_{DDI1} pins must be connected to each other.	
14	V _{DDPA}	-	PS/A	Digital Pad Supply Voltage for Domain A Connect decoupling capacitors to adjacent V _{DDP} /V _{SS} pin pairs as close as possible to the pins. Note: The A/D_Converters and ports P5, P6 and P15 are fed from supply voltage V _{DDPA} .	

Tabla F Din Definitions and Eurotions (cost'd)



Functional Description

to a dedicated vector table location). The occurrence of a hardware trap is also indicated by a single bit in the trap flag register (TFR). Unless another higher-priority trap service is in progress, a hardware trap will interrupt any ongoing program execution. In turn, hardware trap services can normally not be interrupted by standard or PEC interrupts.

Depending on the package option up to 3 External Service Request (ESR) pins are provided. The ESR unit processes their input values and allows to implement user controlled trap functions (System Requests SR0 and SR1). In this way reset, wakeup and power control can be efficiently realized.

Software interrupts are supported by the 'TRAP' instruction in combination with an individual trap (interrupt) number. Alternatively to emulate an interrupt by software a program can trigger interrupt requests by writing the Interrupt Request (IR) bit of an interrupt control register.

3.7 On-Chip Debug Support (OCDS)

The On-Chip Debug Support system built into the XE164xM provides a broad range of debug and emulation features. User software running on the XE164xM can be debugged within the target system environment.

The OCDS is controlled by an external debugging device via the debug interface. This either consists of the 2-pin Device Access Port (DAP) or of the JTAG port conforming to IEEE-1149. The debug interface can be completed with an optional break interface.

The debugger controls the OCDS with a set of dedicated registers accessible via the debug interface (DAP or JTAG). In addition the OCDS system can be controlled by the CPU, e.g. by a monitor program. An injection interface allows the execution of OCDS-generated instructions by the CPU.

Multiple breakpoints can be triggered by on-chip hardware, by software, or by an external trigger input. Single stepping is supported, as is the injection of arbitrary instructions and read/write access to the complete internal address space. A breakpoint trigger can be answered with a CPU halt, a monitor call, a data transfer, or/and the activation of an external signal.

Tracing data can be obtained via the debug interface, or via the external bus interface for increased performance.

Tracing of program execution is supported by the XE166 Family emulation device.

The DAP interface uses two interface signals, the JTAG interface uses four interface signals, to communicate with external circuitry. The debug interface can be amended with two optional break lines.



Functional Description

3.10 General Purpose Timer (GPT12E) Unit

The GPT12E unit is a very flexible multifunctional timer/counter structure which can be used for many different timing tasks such as event timing and counting, pulse width and duty cycle measurements, pulse generation, or pulse multiplication.

The GPT12E unit incorporates five 16-bit timers organized in two separate modules, GPT1 and GPT2. Each timer in each module may either operate independently in a number of different modes or be concatenated with another timer of the same module.

Each of the three timers T2, T3, T4 of **module GPT1** can be configured individually for one of four basic modes of operation: Timer, Gated Timer, Counter, and Incremental Interface Mode. In Timer Mode, the input clock for a timer is derived from the system clock and divided by a programmable prescaler. Counter Mode allows timer clocking in reference to external events.

Pulse width or duty cycle measurement is supported in Gated Timer Mode, where the operation of a timer is controlled by the 'gate' level on an external input pin. For these purposes each timer has one associated port pin (TxIN) which serves as a gate or clock input. The maximum resolution of the timers in module GPT1 is 4 system clock cycles.

The counting direction (up/down) for each timer can be programmed by software or altered dynamically by an external signal on a port pin (TxEUD), e.g. to facilitate position tracking.

In Incremental Interface Mode the GPT1 timers can be directly connected to the incremental position sensor signals A and B through their respective inputs TxIN and TxEUD. Direction and counting signals are internally derived from these two input signals, so that the contents of the respective timer Tx corresponds to the sensor position. The third position sensor signal TOP0 can be connected to an interrupt input.

Timer T3 has an output toggle latch (T3OTL) which changes its state on each timer overflow/underflow. The state of this latch may be output on pin T3OUT e.g. for time out monitoring of external hardware components. It may also be used internally to clock timers T2 and T4 for measuring long time periods with high resolution.

In addition to the basic operating modes, T2 and T4 may be configured as reload or capture register for timer T3. A timer used as capture or reload register is stopped. The contents of timer T3 is captured into T2 or T4 in response to a signal at the associated input pin (TxIN). Timer T3 is reloaded with the contents of T2 or T4, triggered either by an external signal or a selectable state transition of its toggle latch T3OTL. When both T2 and T4 are configured to alternately reload T3 on opposite state transitions of T3OTL with the low and high times of a PWM signal, this signal can be continuously generated without software intervention.



Functional Description

3.12 A/D Converters

For analog signal measurement, up to two 10-bit A/D converters (ADC0, ADC1) with 11 + 5 multiplexed input channels and a sample and hold circuit have been integrated on-chip. 4 inputs can be converted by both A/D converters. Conversions use the successive approximation method. The sample time (to charge the capacitors) and the conversion time are programmable so that they can be adjusted to the external circuit. The A/D converters can also operate in 8-bit conversion mode, further reducing the conversion time.

Several independent conversion result registers, selectable interrupt requests, and highly flexible conversion sequences provide a high degree of programmability to meet the application requirements. Both modules can be synchronized to allow parallel sampling of two input channels.

For applications that require more analog input channels, external analog multiplexers can be controlled automatically. For applications that require fewer analog input channels, the remaining channel inputs can be used as digital input port pins.

The A/D converters of the XE164xM support two types of request sources which can be triggered by several internal and external events.

- Parallel requests are activated at the same time and then executed in a predefined sequence.
- Queued requests are executed in a user-defined sequence.

In addition, the conversion of a specific channel can be inserted into a running sequence without disturbing that sequence. All requests are arbitrated according to the priority level assigned to them.

Data reduction features reduce the number of required CPU access operations allowing the precise evaluation of analog inputs (high conversion rate) even at a low CPU speed. Result data can be reduced by limit checking or accumulation of results.

The Peripheral Event Controller (PEC) can be used to control the A/D converters or to automatically store conversion results to a table in memory for later evaluation, without requiring the overhead of entering and exiting interrupt routines for each data transfer. Each A/D converter contains eight result registers which can be concatenated to build a result FIFO. Wait-for-read mode can be enabled for each result register to prevent the loss of conversion data.

In order to decouple analog inputs from digital noise and to avoid input trigger noise, those pins used for analog input can be disconnected from the digital input stages. This can be selected for each pin separately with the Port x Digital Input Disable registers.

The Auto-Power-Down feature of the A/D converters minimizes the power consumption when no conversion is in progress.

Broken wire detection for each channel and a multiplexer test mode provide information to verify the proper operation of the analog signal sources (e.g. a sensor system).



4.1.2 Operating Conditions

The following operating conditions must not be exceeded to ensure correct operation of the XE164xM. All parameters specified in the following sections refer to these operating conditions, unless otherwise noticed.

Note: Typical parameter values refer to room temperature and nominal supply voltage, minimum/maximum parameter values also include conditions of minimum/maximum temperature and minimum/maximum supply voltage. Additional details are described where applicable.

Parameter	Symbol	Values			Unit	Note /	
		Min. Typ. Max		Max.		Test Condition	
Voltage Regulator Buffer Capacitance for DMP_M	$\begin{array}{c} C_{\rm EVRM} \\ {\rm SR} \end{array}$	1.0	-	4.7	μF	1)	
Voltage Regulator Buffer Capacitance for DMP_1	$C_{\rm EVR1} \ { m SR}$	0.47	-	2.2	μF	1)2)	
External Load Capacitance	$C_{L} \operatorname{SR}$	-	20 ³⁾	-	pF	pin out driver= default	
System frequency	$f_{\rm SYS}{ m SR}$	-	-	100	MHz	5)	
Overload current for analog inputs ⁶⁾	I _{OVA} SR	-2	-	5	mA	not subject to production test	
Overload current for digital inputs ⁶⁾	$I_{\rm OVD}{\rm SR}$	-5	-	5	mA	not subject to production test	
Overload current coupling factor for analog inputs ⁷⁾	K _{OVA} CC	-	2.5 x 10 ⁻⁴	1.5 x 10 ⁻³	-	<i>I</i> _{OV} < 0 mA; not subject to production test	
		_	1.0 x 10 ⁻⁶	1.0 x 10 ⁻⁴	-	<i>I</i> _{OV} > 0 mA; not subject to production test	
Overload current coupling factor for digital I/O pins	K _{OVD} CC	_	1.0 x 10 ⁻²	3.0 x 10 ⁻²		<i>I</i> _{OV} < 0 mA; not subject to production test	
		-	1.0 x 10 ⁻⁴	5.0 x 10 ⁻³		<i>I</i> _{OV} > 0 mA; not subject to production test	

Table 12 Operating Conditions



4.1.3 Pad Timing Definition

If not otherwise noted, all timing parameters are tested and are valid for the corresponding output pins operating in strong driver, fast edge mode. See also "Pad Properties" on Page 103.

4.1.4 Parameter Interpretation

The parameters listed in the following include both the characteristics of the XE164xM and its demands on the system. To aid in correctly interpreting the parameters when evaluating them for a design, they are marked accordingly in the column "Symbol":

CC (Controller Characteristics):

The logic of the XE164xM provides signals with the specified characteristics.

SR (System Requirement):

The external system must provide signals with the specified characteristics to the XE164xM.



4.2.2 DC Parameters for Lower Voltage Area

Keeping signal levels within the limits specified in this table ensures operation without overload conditions. For signal levels outside these specifications, also refer to the specification of the overload current I_{OV} .

Note: Operating Conditions apply.

 Table 14 is valid under the following conditions:

 $V_{\text{DDP}} \ge 3.0 \text{ V}; V_{\text{DDPtvp}} = 3.3 \text{ V}; V_{\text{DDP}} \le 4.5 \text{ V}$

Parameter	Symbol	Values			Unit	Note /
		Min.	Тур.	Max.		Test Condition
Pin capacitance (digital inputs/outputs). To be doubled for double bond pins. ¹⁾	C _{IO} CC	-	-	10	pF	not subject to production test
Input Hysteresis ²⁾	HYS CC	$0.07 ext{ x}$ $V_{ ext{DDP}}$	_	-	V	$R_{\rm S} = 0$ Ohm
Absolute input leakage current on pins of analog ports ³⁾	I _{OZ1} CC	-	10	200	nA	$V_{\rm IN} > V_{\rm SS}; \\ V_{\rm IN} < V_{\rm DDP}$
Absolute input leakage current for all other pins. To be doubled for double	I _{OZ2} CC	-	0.2	2.5	μA	$T_{\rm J} \leq 110 ~^{\rm o}{\rm C};$ $V_{\rm IN} < V_{\rm DDP};$ $V_{\rm IN} > V_{\rm SS}$
bond pins. ³⁾¹⁾⁴⁾		-	0.2	8	μA	$T_{\rm J} \leq 150 ~^{\circ}{\rm C};$ $V_{\rm IN} < V_{\rm DDP};$ $V_{\rm IN} > V_{\rm SS}$
Pull Level Force Current ⁵⁾	$ I_{PLF} $ SR	150	-	-		6)
Pull Level Keep Current ⁷⁾	I _{PLK} SR	-	-	10	μA	6)
Input high voltage (all except XTAL1)	$V_{\rm IH}{\rm SR}$	$0.7 ext{ x}$ $V_{ ext{DDP}}$	-	V _{DDP} + 0.3	V	
Input low voltage (all except XTAL1)	$V_{\rm IL}{ m SR}$	-0.3	-	$0.3 ext{ x}$ $V_{ ext{DDP}}$	V	
Output High voltage ⁸⁾	V _{OH} CC	V _{DDP} - 1.0	-	-	V	$I_{\rm OH} \ge I_{\rm OHmax}$
		V _{DDP} - 0.4	-	-	V	$I_{\rm OH} \ge I_{\rm OHnom}^{9)}$

Table 14 DC Characteristics for Lower Voltage Range



4.2.3 Power Consumption

The power consumed by the XE164xM depends on several factors such as supply voltage, operating frequency, active circuits, and operating temperature. The power consumption specified here consists of two components:

- The switching current $I_{\rm S}$ depends on the device activity
- The leakage current I_{LK} depends on the device temperature

To determine the actual power consumption, always both components, switching current $I_{\rm S}$ and leakage current $I_{\rm LK}$ must be added:

 $I_{\text{DDP}} = I_{\text{S}} + I_{\text{LK}}.$

Note: The power consumption values are not subject to production test. They are verified by design/characterization.

To determine the total power consumption for dimensioning the external power supply, also the pad driver currents must be considered.

The given power consumption parameters and their values refer to specific operating conditions:

Active mode:

Regular operation, i.e. peripherals are active, code execution out of Flash.

Stopover mode:

Crystal oscillator and PLL stopped, Flash switched off, clock in domain DMP_1 stopped.

Note: The maximum values cover the complete specified operating range of all manufactured devices.

The typical values refer to average devices under typical conditions, such as nominal supply voltage, room temperature, application-oriented activity.

After a power reset, the decoupling capacitors for $V_{\rm DDIM}$ and $V_{\rm DDI1}$ are charged with the maximum possible current.

For additional information, please refer to Section 5.2, Thermal Considerations.

Note: Operating Conditions apply.

Parameter	Symbol	Values			Unit	Note /
		Min.	Тур.	Max.		Test Condition
Power supply current (active) with all peripherals active and EVVRs on	I _{SACT} CC	_	$10 + 0.6 x f_{SYS}^{1)}$	10 + 1.0 x $f_{SYS}^{1)}$	mA	2)3)
Power supply current in stopover mode, EVVRs on	$I_{\rm SSO}$ CC	-	0.7	2.0	mA	

Table 15 Switching Power Consumption

1) $f_{\rm SYS}$ in MHz.



2) The pad supply voltage pins (V_{DDPB}) provide the input current for the on-chip EVVRs and the current consumed by the pin output drivers. A small current is consumed because the drivers input stages are switched.

In Fast Startup Mode (with the Flash modules deactivated), the typical current is reduced to $3 + 0.6 \text{ x} f_{SYS}$.

3) Please consider the additional conditions described in section "Active Mode Power Supply Current".

Active Mode Power Supply Current

The actual power supply current in active mode not only depends on the system frequency but also on the configuration of the XE164xM's subsystem.

Besides the power consumed by the device logic the power supply pins also provide the current that flows through the pin output drivers.

A small current is consumed because the drivers' input stages are switched.

The IO power domains can be supplied separately. Power domain A ($V_{\rm DDPA}$) supplies the A/D converters and Port 6. Power domain B ($V_{\rm DDPB}$) supplies the on-chip EVVRs and all other ports.

During operation domain A draws a maximum current of 1.5 mA for each active A/D converter module from $V_{\rm DDPA}$.

In Fast Startup Mode (with the Flash modules deactivated), the typical current is reduced to $(3 + 0.6 \times f_{SYS})$ mA.



Sample time and conversion time of the XE164xM's A/D converters are programmable. The timing above can be calculated using **Table 18**.

The limit values for f_{ADCI} must not be exceeded when selecting the prescaler value.

GLOBCTR.5-0 (DIVA)	A/D Converter Analog Clock f_{ADCI}	INPCRx.7-0 (STC)	Sample Time ¹⁾ t _s
000000 _B	f _{SYS}	00 _H	$t_{ADCI} \times 2$
000001 _B	f _{SYS} / 2	01 _H	$t_{\sf ADCI} imes {f 3}$
000010 _B	f _{SYS} / 3	02 _H	$t_{ADCI} \times 4$
:	$f_{\rm SYS}$ / (DIVA+1)	:	$t_{ADCI} \times (STC+2)$
111110 _B	f _{SYS} / 63	FE _H	$t_{\rm ADCI} imes 256$
111111 _B	f _{SYS} / 64	FF _H	$t_{\rm ADCI} imes 257$

 Table 18
 A/D Converter Computation Table

1) The selected sample time is doubled if broken wire detection is active (due to the presampling phase).

Converter Timing Example A:

Assumptions:	$f_{\rm SYS}$	= 80 MHz (i.e. t_{SYS} = 12.5 ns), DIVA = 03 _H , STC = 00 _H
Analog clock	$f_{\rm ADCI}$	$= f_{SYS} / 4 = 20 \text{ MHz}$, i.e. $t_{ADCI} = 50 \text{ ns}$
Sample time	t _S	$= t_{ADCI} \times 2 = 100 \text{ ns}$
Conversion 10-	bit:	
	t _{C10}	= $13 \times t_{ADCI}$ + $2 \times t_{SYS}$ = 13×50 ns + 2×12.5 ns = 0.675 µs
Conversion 8-b	it:	
	t _{C8}	= $11 \times t_{ADCI}$ + $2 \times t_{SYS}$ = 11×50 ns + 2×12.5 ns = 0.575 µs

Converter Timing Example B:

Assumptions:	$f_{\rm SYS}$	= 40 MHz (i.e. t_{SYS} = 25 ns), DIVA = 02 _H , STC = 03 _H
Analog clock	$f_{\rm ADCI}$	$= f_{SYS} / 3 = 13.3 \text{ MHz}$, i.e. $t_{ADCI} = 75 \text{ ns}$
Sample time	t _S	$= t_{ADCI} \times 5 = 375 \text{ ns}$
Conversion 10-	bit:	
	<i>t</i> _{C10}	= $16 \times t_{ADCI}$ + $2 \times t_{SYS}$ = 16×75 ns + 2×25 ns = $1.25 \ \mu s$
Conversion 8-b	it:	
	t _{C8}	= $14 \times t_{ADCI}$ + $2 \times t_{SYS}$ = 14×75 ns + 2×25 ns = 1.10 µs



4.4 System Parameters

The following parameters specify several aspects which are important when integrating the XE164xM into an application system.

Note: These parameters are not subject to production test but verified by design and/or characterization.

Note: Operating Conditions apply.

Parameter	Symbol	Values			Unit	Note /
		Min.	Тур.	Max.	1	Test Condition
Short-term deviation of internal clock source frequency ¹⁾	∆f _{INT} CC	-1	_	1	%	⊿ <i>T</i> _J ≤ 10 °C
Internal clock source frequency	$f_{\rm INT}{\rm CC}$	4.8	5.0	5.2	MHz	
Wakeup clock source frequency ²⁾	f _{₩U} CC	400	-	700	kHz	FREQSEL= 00
		210	-	390	kHz	FREQSEL= 01
		140	-	260	kHz	FREQSEL= 10
		110	-	200	kHz	FREQSEL= 11
Startup time from power- on with code execution from Flash	t _{SPO} CC	1.8	2.2	2.7	ms	$f_{\rm WU}$ = 500 kHz
Startup time from stopover mode with code execution from PSRAM	t _{SSO} CC	11 / f _{WU} ³⁾	_	12 / f _{WU} ³⁾	μS	
Core voltage (PVC) supervision level	V _{PVC} CC	V _{LV} - 0.03	V _{LV}	V _{LV} + 0.07 ₄₎	V	5)
Supply watchdog (SWD) supervision level	V _{SWD} CC	V _{LV} - 0.10 ⁶⁾	$V_{\rm LV}$	V _{LV} + 0.15	V	Lower voltage range ⁵⁾
		V _{LV} - 0.15	$V_{\rm LV}$	V _{LV} + 0.15	V	Upper voltage range ⁵⁾

Table 19 Various System Parameters

 The short-term frequency deviation refers to a timeframe of a few hours and is measured relative to the current frequency at the beginning of the respective timeframe. This parameter is useful to determine a time span for re-triggering a LIN synchronization.

 This parameter is tested for the fastest and the slowest selection. The medium selections are not subject to production test - verified by design/characterization



4.6 AC Parameters

These parameters describe the dynamic behavior of the XE164xM.

4.6.1 Testing Waveforms

These values are used for characterization and production testing (except pin XTAL1).

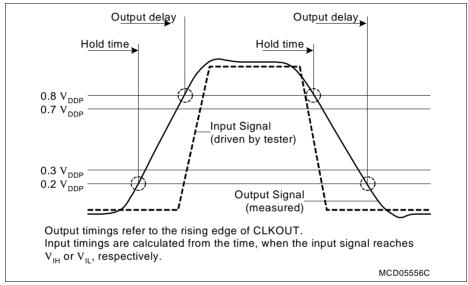
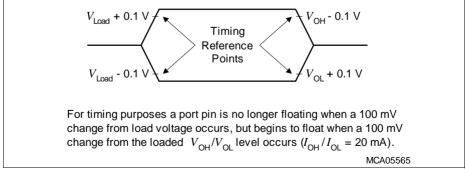


Figure 17 Input Output Waveforms







4.6.2 Definition of Internal Timing

The internal operation of the XE164xM is controlled by the internal system clock f_{SYS} .

Because the system clock signal $f_{\rm SYS}$ can be generated from a number of internal and external sources using different mechanisms, the duration of the system clock periods (TCSs) and their variation (as well as the derived external timing) depend on the mechanism used to generate $f_{\rm SYS}$. This must be considered when calculating the timing for the XE164xM.

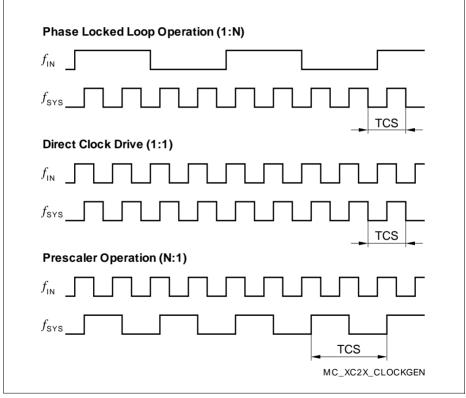


Figure 19 Generation Mechanisms for the System Clock

Note: The example of PLL operation shown in **Figure 19** uses a PLL factor of 1:4; the example of prescaler operation uses a divider factor of 2:1.

The specification of the external timing (AC Characteristics) depends on the period of the system clock (TCS).



Table 29 EBC External Bus Timing for Upper Voltage Range

Parameter	Symbol	Values			Unit	Note /
		Min.	Тур.	Max.	-	Test Condition
$\frac{\text{Output valid delay for }\overline{\text{RD}},}{\text{WR}(\text{L/H})}$	<i>t</i> ₁₀ CC	-	7	13	ns	
Output valid delay for BHE, ALE	<i>t</i> ₁₁ CC	-	7	14	ns	
Address output valid delay for A23 A0	<i>t</i> ₁₂ CC	_	8	14	ns	
Address output valid delay for AD15 AD0 (MUX mode)	<i>t</i> ₁₃ CC	_	8	15	ns	
Output valid delay for CS	t ₁₄ CC	-	7	13	ns	
Data output valid delay for AD15 AD0 (write data, MUX mode)	<i>t</i> ₁₅ CC	_	8	15	ns	
Data output valid delay for D15 D0 (write data, DEMUX mode)	<i>t</i> ₁₆ CC	_	8	15	ns	
Output hold time for \overline{RD} , WR(L/H)	<i>t</i> ₂₀ CC	-2	6	8	ns	
Output hold time for BHE, ALE	<i>t</i> ₂₁ CC	-2	6	10	ns	
Address output hold time for AD15 AD0	<i>t</i> ₂₃ CC	-3	6	8	ns	
Output hold time for CS	t ₂₄ CC	-3	6	11	ns	
Data output hold time for D15 D0 and AD15 AD0	<i>t</i> ₂₅ CC	-3	6	8	ns	
Input setup time for READY, D15 D0, AD15 AD0	<i>t</i> ₃₀ SR	25	15	-	ns	
Input hold time READY, D15 D0, AD15 AD0 ¹⁾	<i>t</i> ₃₁ SR	0	-7	-	ns	

 Read data are latched with the same internal clock edge that triggers the address change and the rising edge of RD. Address changes before the end of RD have no impact on (demultiplexed) read cycles. Read data can change after the rising edge of RD.



Electrical Parameters

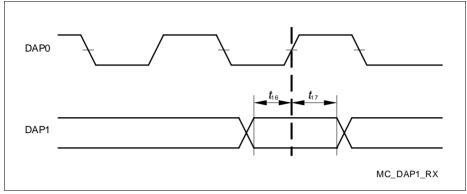


Figure 28 DAP Timing Host to Device

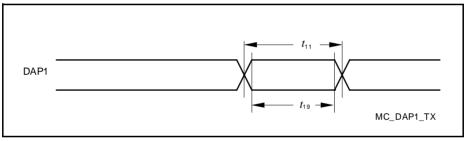


Figure 29 DAP Timing Device to Host

Note: The transmission timing is determined by the receiving debugger by evaluating the sync-request synchronization pattern telegram.